



JST12C-800

Peak pulse voltage ($T_j=25$; non-repetitive, off-state; FIG. 7)	V_{pp}	3.5	kV
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ELECTRICAL CHARACTERISTICS ($T_j=25$ unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I_{GT}	$V_D=12V$ $R_L=33$	- -	MAX.	5	mA
V_{GT}		- -	MAX.	1	V
V_{GD}	$V_D=V_{DRM}$ $T_j=125$ $R_L=3.3k$	- -	MIN.	0.2	V
I_L	$I_G=1.2I_{GT}$	-	MAX.	10	mA
				15	
I_H	$I_T=500mA$		MAX.	10	mA
dV/dt (dI/dt)c	$V_D=540V$ Gate Open $T_j=125$ (dV/dt)c=1		MIN. MIN-	80	V s

ORDERING INFORMATION -

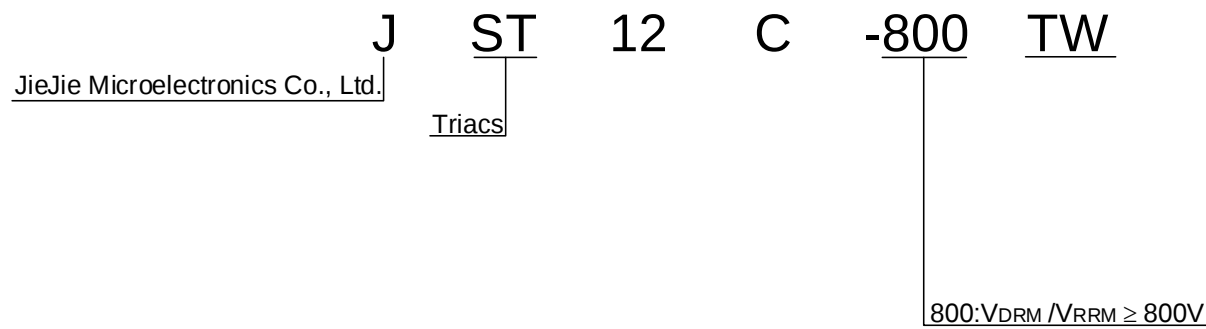


FIG.1: Maximum power dissipation versus RMS on-state current

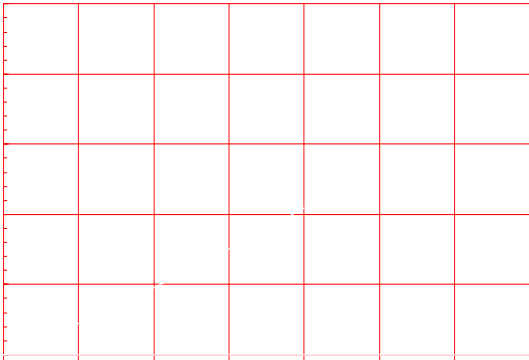


FIG.2: RMS on-state current versus case temperature

ORDERING INFORMATION

Order code	Voltage V _{DRM} /V _{RRM} (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		- -			
JST12C-800TW	800	5	TO-220C	50	Tube

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